

UTC UNISONIC TECHNOLOGIES CO., LTD

DTC143T

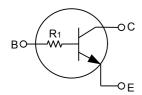
NPN SILICON TRANSISTOR

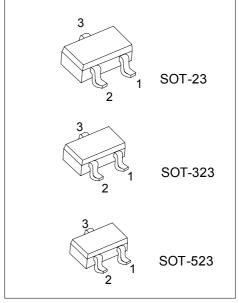
NPN DIGITAL TRANSISTOR (BUILT- IN BIAS RESISTORS)

FEATURES

- * Built-in bias resistors that implies easy ON/OFF applications.
- * The bias resistors are thin-film resistors with complete isolation to allow negative input.

EQUIVALENT CIRCUIT

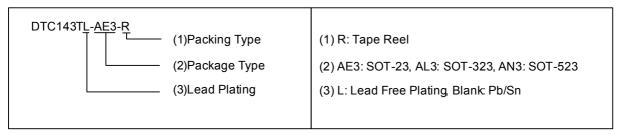




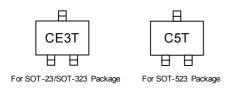
^{*} Pb-free plating product number: DTC143TL

ORDERING INFORMATION

Order Number		Daakaga	Pin A	Assign	Dooking	
Normal	Lead Free Plating www.D	Package ataSheet4U.com	1	2	3	Packing
DTC143T-AE3-R	DTC143TL-AE3-R	SOT-23	Е	В	C	Tape Reel
DTC143T-AL3-R	DTC143TL-AL3-R	SOT-323	E	В	С	Tape Reel
DTC143T-AN3-R	DTC143TL-AN3-R	SOT-523	Е	В	С	Tape Reel



MARKING



www.unisonic.com.tw 1of 3 QW-R206-059,D

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

PARAMETE	SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Collector Current	Ic	100	mA	
Callester Bayyar Dissination	SOT-523	Б	150	mW
ollector Power Dissipation	SOT-23/SOT-323	P _C	200	mW
Junction Temperature		TJ	+150	
Storage Temperature	T _{STG}	-55~+150		

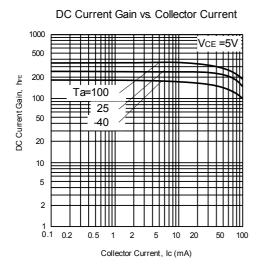
Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

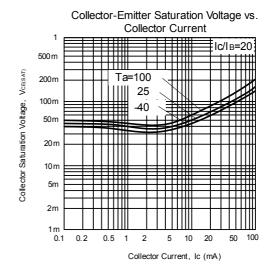
■ **ELECTRICAL CHARACTERISTICS** (Ta=25°C, unless otherwise specified.)

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_CBO	I _C =50μA	50			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA	50			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =50μA	5			V
Collector Cut-off Current	I _{CBO}	V _{CB} =50V			0.5	μΑ
Emitter Cut-off Current	I _{EBO}	V _{EB} =4V			0.5	μΑ
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I_C =5mA, I_B =0.25mA			0.3	V
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =1mA	100	250	600	
Input Resistance	R ₁		3.29	4.7	6.11	kΩ
Transition Frequency	f _T	V _{CE} =10V, I _E =5mA, f=100MHz *		250		MHz

^{*} Transition frequency of the device.

■ TYPICAL CHARACTERISTICS





UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.